

RM400DY-66S

HIGH POWER SWITCHING USE
INSULATED TYPE

High Voltage Diode Module

RM400DY-66S



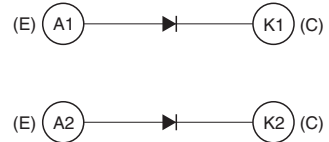
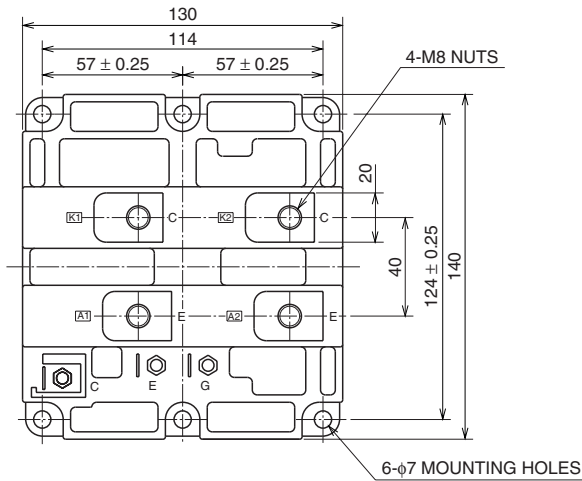
- IF 400A
- VRRM 3300V
- Insulated Type
- 2-element in a Pack
- Copper Baseplate

APPLICATION

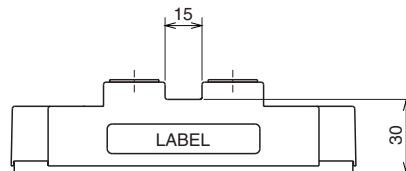
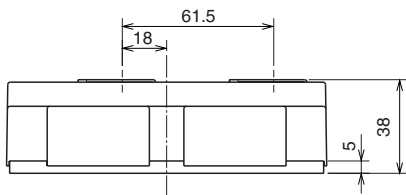
Traction drives, High Reliability Converters / Inverters, DC choppers

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



CIRCUIT DIAGRAM



High Voltage Diode Module

RM400DY-66S

**HIGH POWER SWITCHING USE
INSULATED TYPE**

High Voltage Diode Module

MAXIMUM RATINGS

Symbol	Item	Conditions	Ratings	Unit
VRRM	Repetitive peak reverse voltage	T _j = 25 °C	3300	V
VRSM	Non-repetitive peak reverse voltage	T _j = 25 °C	3300	V
VR(DC)	Reverse DC voltage	T _j = 25 °C	2200	V
IF	DC forward current	T _c = 25 °C	400	A
IFSM	Surge forward current	T _j = 25 °C start, t _w = 8.3 ms Half sign wave	3200	A
i ² t	Current-squared, time integration	T _j = 25 °C start, t _w = 8.3 ms Half sign wave	42.7	kA ² s
V _{iso}	Isolation voltage	Charged part to the baseplate RMS sinusoidal, 60Hz 1min.	6000	V
T _j	Junction temperature	—	-40 ~ +150	°C
T _{op}	Operating temperature	—	-40 ~ +125	°C
T _{stg}	Storage temperature	—	-40 ~ +125	°C

ELECTRICAL CHARACTERISTICS

Symbol	Item	Conditions	Limits			Unit
			Min	Typ	Max	
IRRM	Repetitive reverse current	V _{RM} = VRRM	T _j = 25 °C	—	3.0	mA
			T _j = 125 °C	—	10	
VFM	Forward voltage (Note 1)	I _F = 400 A	T _j = 25 °C	—	4.55	V
			T _j = 125 °C	—	3.75	
t _{rr}	Reverse recovery time	V _R = 1650 V, I _F = 400 A di/dt = -800 A/μs L _s =200nH, T _j = 125 °C	—	0.75	—	μs
I _{rr}	Reverse recovery current		—	300	—	A
Q _{rr}	Reverse recovery charge		—	200	—	μC
E _{rec}	Reverse recovery energy (Note 2)		—	0.15	—	J/P

Note 1. It doesn't include the voltage drop by internal lead resistance.
2. E_{rec} is the integral of 0.1V_Rx 0.1I_{rr}x dt.

RM400DY-66S

**HIGH POWER SWITCHING USE
INSULATED TYPE**

High Voltage Diode Module

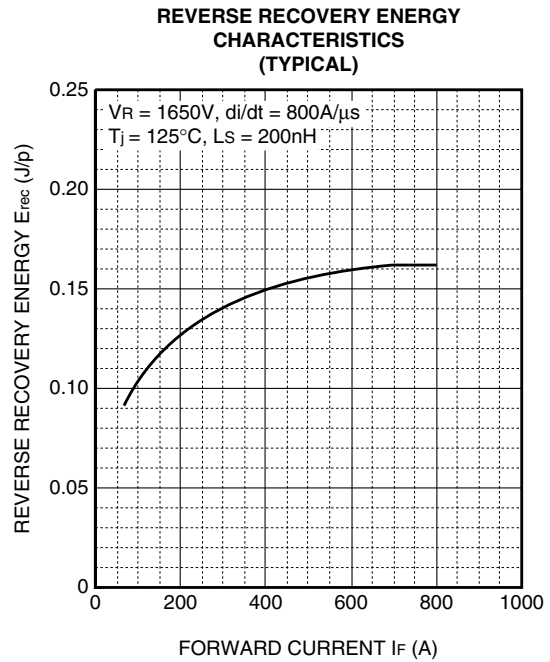
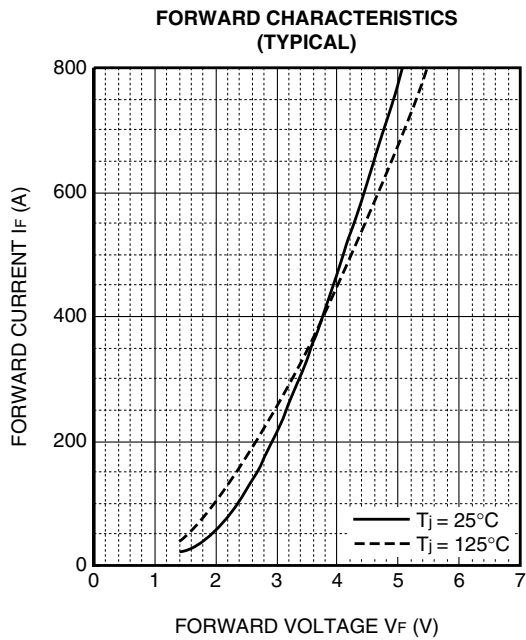
THERMAL CHARACTERISTICS

Symbol	Item	Conditions	Limits			Unit
			Min	Typ	Max	
R _{th(j-c)}	Thermal resistance	Junction to case (per 1/2 module)	—	—	72.0	K/kW
R _{th(c-f)}	Contact thermal resistance	Case to Fin, λ _{grease} = 1W/m-K D _(c-f) =100μm, (per 1/2 module)	—	36.0	—	K/kW

MECHANICAL CHARACTERISTICS

Symbol	Item	Conditions	Limits			Unit
			Min	Typ	Max	
M _t	Mounting torque	M8: Main terminals screw	6.67	—	8.24	N·m
M _s		M6: Mounting screw	2.84	—	3.43	N·m
m	Mass	—	—	1.5	—	kg

PERFORMANCE CURVES



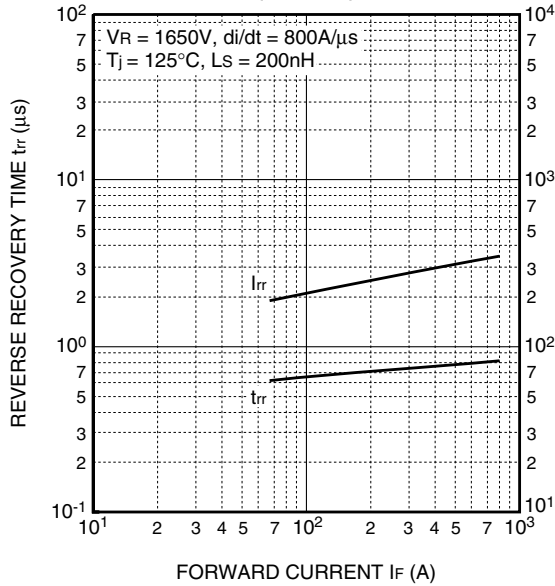
High Voltage Diode Module

RM400DY-66S

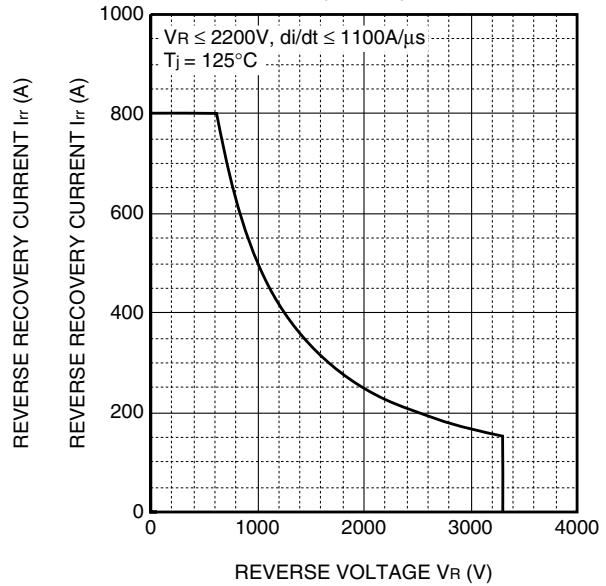
**HIGH POWER SWITCHING USE
INSULATED TYPE**

High Voltage Diode Module

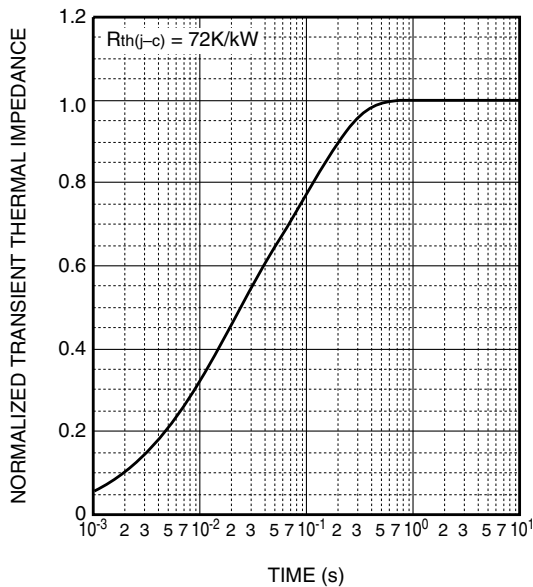
REVERSE RECOVERY CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY SAFE OPERATING AREA (RRSOA)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS



High Voltage Diode Module